NSN 5961-01-147-2386



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-147-2386 **Inclosure Material:** Metal **Overall Length:** Between 0.790 inches and 0.810 inches **Overall Height:** Between 0.085 inches and 0.105 inches Overall Width: Between 0.252 inches and 0.268 inches **End Application:** 5820-01-048-9110 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 3.5 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 44.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals and base surface gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 flange and 2 ribbon Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

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